

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Jong-Lam LEE

Serial No.: 10/597,200

Confirmation No.: 7656

Filed: July 14, 2006

Docket No.: P2381US00

Group Art Unit: 2818

Examiner: NGUYEN, Thinh T.

For: **GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR DEVICE
AND METHOD OF MANUFACTURING THE SAME**

Mail Stop ISSUE FEE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE

Sir:

Applicant appreciates the indication in the Notice of Allowance dated September 9, 2010 that claims 1-7 and 12-17 are allowed. While Applicant agrees these claims are patentable over the cited references, Applicant does not agree that patentability resides in each feature exactly as expressed in the claims, nor that each feature is required for patentability of each claim.

Respectfully Submitted,

/hae-chan park/

Hae-Chan Park
Reg. No. 50,114

Date: November 19, 2010

CUSTOMER NUMBER: 58027
HCP/TDH/kca